

Features

- * Up to 93% Efficient Boost Converter
- * Integrated 80mΩ Power MOSFET
- * 2V to 24V Input Voltage
- * 1.2MHz Fixed Switching Frequency
- * Internal 4A Switch Current Limit
- * Adjustable Output Voltage up to 28V
- * Internal Compensation
- * Automatic Pulse Frequency Modulation

 Mode at Light Loads
- * Available in Green SOT23-6 Package

Applications

- * Battery-Powered Equipment
- * Set-Top Boxed
- * LCD Bais Supply
- * DSL and Cable Modems and Routers
- * Networking cards Powered from PCI or PCI express slots

General Description

The HCR6628 is a constant frequency, SOT23-6 current mode step-up converter intended for small, low power applications. The HCR6628 switches at 1.2MHz and allows the use of tiny, low cost capacitors and inductors 2mm or less in height. Internal soft-start results in small inrush current and extends battery life. The HCR6628 features automatic shifting to pulse frequency modulation mode at light loads. The HCR6628 includes under-voltage lockout, current limiting, and thermal overload protection to prevent damage in the event of an output overload. The HCR6628 is available in a small SOT23-6 package.



SOT23-6

Figure 1. Package Type of HCR6628



Pin Configuration

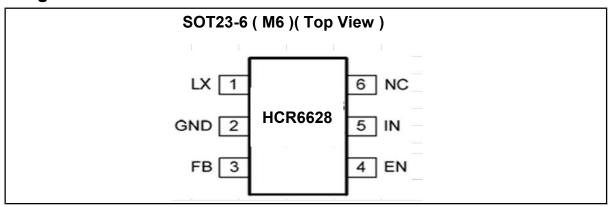
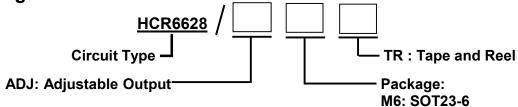


Figure 2. Pin Configuration of HCR6628 (Top View)

Pin Function Table

Pin	Pin Name	Function
1	LX	Power Switch Output. LX is the drain of the internal MOSFET switch. Connect the power inductor and output rectifier to LX. LX can swing between GND and 28V.
2	GND	Ground pin
3	FB	Feedback Input. The FB voltage is 0.6V. Connect a resistor divider to FB.
4	EN	Regulator On/off control input. A high input at EN turns on the converter, and a low input turns it off. When not used, connect EN to the input supply for automatic startup.
5	IN	Input Supply Pin. Must be locally bypassed.
6	NC	Not Connection.

Ordering Information



Ordering Code

Part Number	Marking ID noteA	Temperature Range	Package	Quantity per Reel	
HCR6628/ADJM6TR	B628XY	-40'C to +85'C	SOT-23-6	3000pcs/TR	

note A. X=Year code and Y=week code



Absolute Maximum Ratings Note 1

Parameter	Symbol	Value	Unit
Input Voltage Voltage	Vin	-0.3 to 26	V
LX Voltage	VLX	-0.3 to 30	V
EN Voltage	VEN	-0.3 to 26	V
FB Voltage	VFB	-0.3 to 6	V
Continuous Power Dissipation	PD	600	mW
Thermal Resistance Junction to Ambient	Reja	250	'C/W
Thermal Resistance Junction to Case	Rejc	130	'C/W
Junction Temperature note2	TJ	160	'C
Storage Temperature Range	ТЅТС	-65 to 150	'C
Lead Temperature (Soldering, 10s)	TLEAD	300	'C
Human Body Model	ESD HBM	2000	V
Machine Mode	ESD MM	200	V

Recommend Operating Conditions note2

Reliable Operating Input Voltage Range	Vcc	2.0 to 24	٧
Operting Temperature Range	TA	-40 to +85	Ċ.

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

2: TJ is calculated from the ambient temperature TA and power dissipation PD according to the following

formula: $TJ = TA + (PD) \times (250^{\circ}C/W)$.



Electrical Characteristics note3

(VIN=VEN=5V, Typical values are at TA=+25'C, unless otherwise noted.)

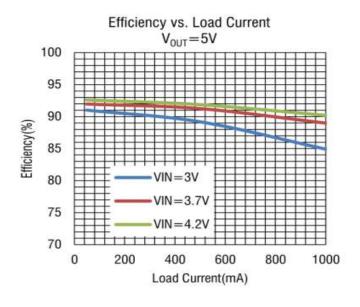
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Parameter	Symbol	Test Condition	Min	Туре	Max	Unit
Operating Input Voltage	Vin	Vin < 0.9Vout	2.0	-	24	٧
Under Voltage Lockout	VLKT		-	-	1.98	٧
Under Voltage Lockout Hysteresis	VLKT-Hys		-	100	1	mV
Current (Shutdown)	Ishdn	VEN=0V	-	0.1	1.0	uA
Quiescent Current(PFM)	IQ1	V _{FB} =0.7V, No switch	-	100	200	uA
Quiescent Current(PWM)	lQ2	V _{FB} =0.5V, switch	1	1.0	2.2	mA
Switching Frequency	f		-	1.2	-	MHz
Maximum Duty Cycle	ŋ	V _{FB} =0V	93	-	-	%
EN "High" Voltage	VIH	-	1.5	-	-	٧
EN"Low" Voltage	VIL	-	-	•	0.4	٧
FB Voltage	VFB		0.588	0.6	0.612	٧
FB Input Bias Current	IFB	VFB=0.6V	-50	-10	-	nA
LX On Resistance	RLX-RES	-	-	80	150	mΩ
LX Current Limite	ILX	VIN=5V, Duty cycle=50%	-	4	•	Α
LX Leakage	ILX-LKG	VLX=20V	-	-	1	uA
Over Temperature Shutdown	Тѕно		-	155	-	'C
Over Temperature Hysteresis	THYS		-	20	-	'C
	•	•				

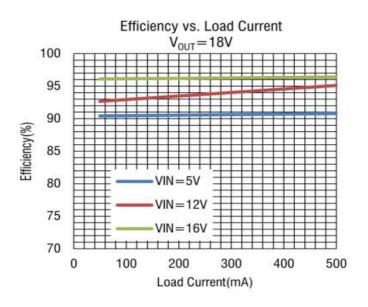
Note 1. Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

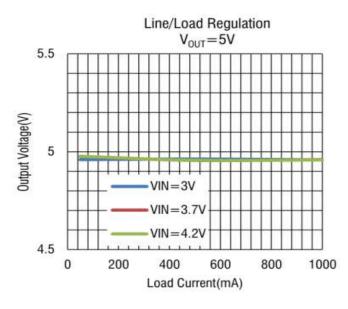
- 2. TJ is calculated from the ambient temperature TA and power dissipation PD according to the following TJ=tA+(PD)X(250'C/W)
- 3. 100% production test at 25°C. Specifications over the temperature range are guaranteed by design and characterization.
- 4. Dynamic supply current is higher due to the gate charge being devlivered at the switching frequency

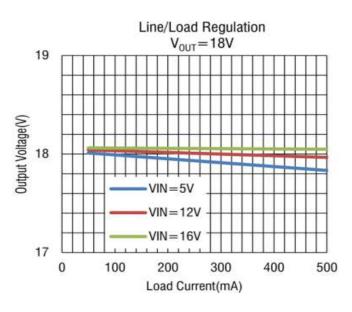


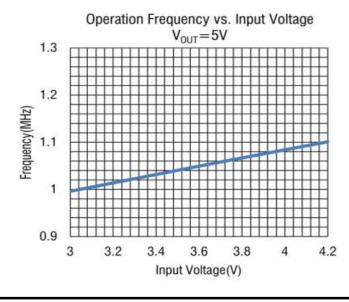
TYPICAL PERFORMANCE CHARACTERISTICS

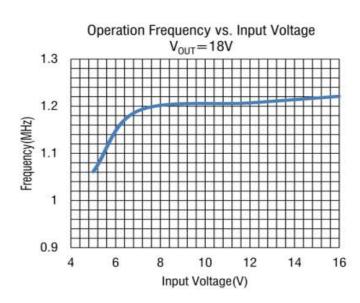














Functional Block Diagram

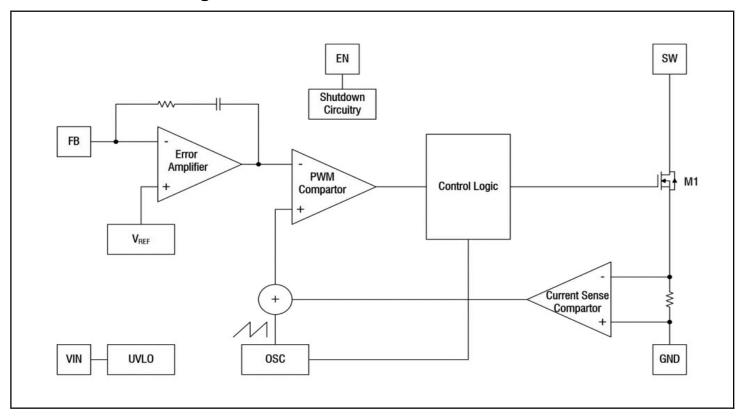


Figure 3. Functional Block Diagram of HCR6628

Typical Application

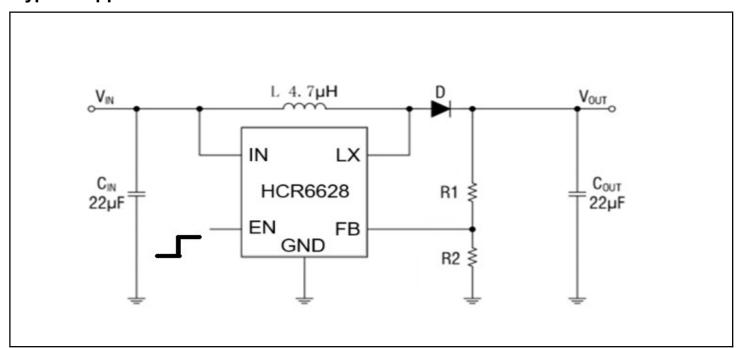


Figure 4. Typical Application Circuit of HCR6628



Operation

The HCR6628 uses a fixed frequency, peak current mode boost regulator architecture to regulate voltage at the feedback pin. The operation of the HCR6628 can be understood by referring to the block diagram of Figure 2. At the start of each oscillator cycle the MOSFET is turned on through the control circuitry. To prevent sub-harmonic oscillations at duty cycles greater than 50 percent, a stabilizing ramp is added to the output of the current sense amplifier and the result is fed into the negative input of the PWM comparator. When this voltage equals The output voltage of the error amplifier the power

MOSFET is turned off. The voltage at the output of the error amplifier is an amplified version of the difference between the 0.6V bandgap reference voltage and the feedback voltage. In this way the peak current level keeps the output in regulation. If the feedback voltage starts to drop, the output of the error amplifier increases. These results in more current to flow through the power MOSFET, thus increasing the power delivered to the output. The HCR6628 has internal soft start to limit the amount of input current at startup and to also limit the amount of overshoot on the output.

Typical Application

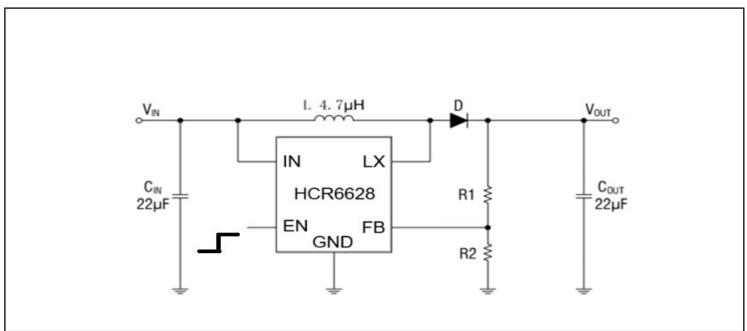


Figure 5. Typical Application Circuit of HCR6628



Application Information

Setting the Output Voltage

The internal reference VREF is 0.6V (Typical). The output voltage is divided by a resistor divider,R1 and R2 to the FB pin. The output voltage is given by

Inductor Selection

The recommended values of inductor are 4.7 to 22µH. Small size and better efficiency are the major concerns for portable device, such as HCR6628 used for mobile phone. The inductor should have low core loss at 1.2MHz and low DCR for better efficiency. To avoid inductor saturation current rating should be considered.

Capacitor Selection

Input and output ceramic capacitors of 22µF are recommended for HCR6628 applications. For better voltage filtering, ceramic capacitors with low ESR are recommended. X5R and X7R types are suitable because of their wider voltage and temperature ranges.

Diode Selection

Schottky diode is a good choice for HCR6628 because of its low forward voltage drop and fast reverses recovery. Using Schottky diode can get better efficiency. The high speed rectification is also a good characteristic of

Diode Selection (con.)

Schottky diode for high switching frequency.

Current rating of the diode must meet the root mean square of the peak current and output average current multiplication as following

$$I_D(RMS) \approx \sqrt{I_{OUT} \times I_{PEAK}}$$

The diode's reverse breakdown voltage should be larger than the output voltage.

Layout Consideration

For best performance of the HCR6628, the following guidelines must be strictly followed.

- a>. Input and Output capacitors should be placed close to the IC and connected to ground plane to reduce noise coupling.
- b>. The GND should be connected to a strong ground plane for heat sinking and noise protection.
- c>. Keep the main current traces as possible as short and wide.
- d>. LX node of DC-DC converter is with high frequency voltage swing. It should be kept at a small area.
- e>.Place the feedback components as close as possible to the IC and keep away from the noisy devices.

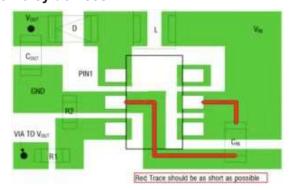


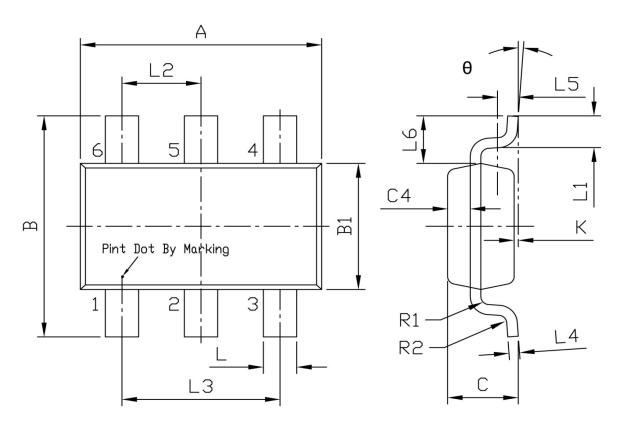
Figure 6. HCR6628 Suggested Layout



Mechanical Dimensions

PKG: SOT23-6 (M6)

Unit:mm



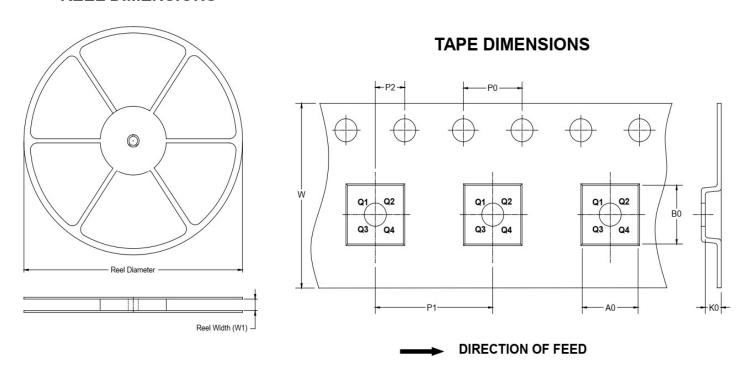
Unit: mm

Symbol	Dime	nsions In Millin	neters	Symbol	Dimensions In Millimeters			
Syllibol	Min T		Max	Syllibol	Min	Тур	Max	
Α	2.80	2.90	3.00	L3	1.800	1.900	2.000	
В	2.60	2.80	3.00	L4	0.077	0.127	0.177	
B1	1.50	1.60	1.70	L5	-	0.250	-	
С	-	2	1.05	L6	120	0.600	4	
C1	0.60	0.80	1.00	θ	0°		0°	
C2	0.35	0.40	0.45	Θ1	10°	12°	14°	
C4	0.223	0.273	0.323	Θ2	10°	12°	14°	
K	0.000	0.075	0.150	R	-	0.100	-	
L	0.325	0.400	0.475	R1	(2)	0.100	<u>=</u>	
L1	0.325	0.450	0.550	R2	-	0.100	-	
L2	0.850	0.950	1.050					



TAPE AND REEL INFORMATION

REEL DIMENSIONS



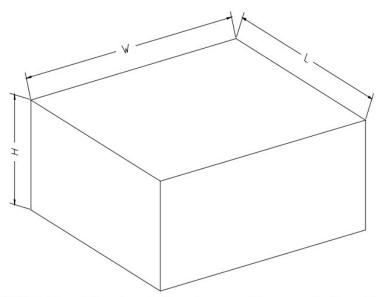
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1	A0	В0	K0	P0	P1	P2	w	Pin1
71-		(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	Quadrant
SOT23-6	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3



CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
7"	442	410	224	18	